DESCRIPTION
The MP2637A is a highly-integrated, flexible, switch-mode battery charger with system power path management designed for single-cell Li-ion or Li-polymer batteries for use in a wide range of applications.

The MP2637A can operate in both charge mode and boost mode to allow for full system and battery power management.

When the input power is present, the MP2637A operates in charge mode. The MP2637A detects the battery voltage automatically and charges the battery in three phases: trickle current, constant current, and constant voltage. Other features include charge termination and auto-recharge. The MP2637A also integrates both input current limit and input voltage regulation to manage the input power and meet the system power demand priority.

In the absence of an input source, the MP2637A switches to boost mode through MODE to power the SYS pins from the battery. The OLIM pin programs the output current limit in boost mode. The MP2637A also allows for output short-circuit protection (SCP) to disconnect the battery completely from the load in the event of a short-circuit fault. Normal operation resumes once the short-circuit fault is removed. The MP2637A provides full operating status indication to distinguish charge mode from boost mode.

To guarantee safe operation, the MP2637A limits the die temperature to a preset value of 120°C. Other safety features include input over-voltage protection (OVP), battery over-voltage protection (OVP), thermal shutdown, battery temperature monitoring, and a programmable timer to prevent prolonged charging of a dead battery.

The MP2637A is available in a QFN-24 (4mmx4mm) package.

FEATURES
- Up to 16V Sustainable Input Voltage
- 4.5V to 6V Operating Input Voltage Range
- Power Management Function, Integrated Input Current Limit, Input Voltage Regulation
- Up to 2.5A Programmable Charge Current
- Trickle-Charge Function
- Selectable 4.20V/4.055V Charge Voltage with 0.5% Accuracy
- Negative Temperature Coefficient Pin (NTC) for Battery Temperature Monitoring
- Programmable Timer Back-Up Protection
- Thermal Regulation and Thermal Shutdown
- Internal Battery Reverse Leakage Blocking
- Integrated Over-Voltage Protection (OVP) and Over-Current Protection (OCP) for Pass-Through Path
- Reverse Boost Operation Mode for System Power
- Up to 2.4A Programmable Output Current Limit for Boost Mode
- Integrated Short-Circuit Protection (SCP) and Output Over-Voltage Protection (OVP) for Boost Mode
- Available in a QFN-24 (4mmx4mm) Package

APPLICATIONS
- Sub-Battery Applications
- Power-Bank Applications for Smartphones, Tablet, and Other Portable Devices

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TYPICAL APPLICATION

*NOTES:*
1. \( R_{OLIM} \) cannot be lower than 47.5kΩ. \( R_{OLIM} \) is for the boost output current loop setting. Refer to the Application Information section on page 31 for details.
2. Place \( C_{SYS} \) as close to SYS and PGND as possible. The capacitor is recommended to be at least 22μF. \( C_{SYS} + C_2 \) should not be less than 44μF. Ceramic capacitors are recommended; E-caps are not recommended.
3. The VCC cap should not exceed 100nF (recommend 47nF or 100nF).
4. The inductor should not exceed 2.2μH (recommend 1.5μH or 2.2μH).
### Table 1: Operation Mode

<table>
<thead>
<tr>
<th>Power Source</th>
<th>MODE</th>
<th>EN</th>
<th>Operating Mode</th>
<th>ACOK</th>
<th>Q1, Q2</th>
<th>Q3</th>
<th>Q4</th>
</tr>
</thead>
<tbody>
<tr>
<td>VIN &gt; VBATT + 300mV</td>
<td>0.8V &lt; PWIN &lt; 1.15V</td>
<td>X</td>
<td>Low</td>
<td>Only pass-through mode</td>
<td>Low</td>
<td>On</td>
<td>Off</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>High</td>
<td>Charging mode</td>
<td></td>
<td>On</td>
<td>SW</td>
</tr>
<tr>
<td>PWIN &lt; 0.8V or PWIN &gt; 1.15V</td>
<td></td>
<td></td>
<td>High</td>
<td>Boost discharge mode</td>
<td>High</td>
<td>Off</td>
<td>SW</td>
</tr>
<tr>
<td>VIN &lt; VBATT + 300mV</td>
<td>X</td>
<td></td>
<td>Low</td>
<td>SYS force-off mode</td>
<td>High</td>
<td>Off</td>
<td>Off</td>
</tr>
<tr>
<td>PWIN &lt; 0.8V or PWIN &gt; 1.15V</td>
<td></td>
<td></td>
<td>Low</td>
<td>Sleep mode</td>
<td>High</td>
<td>Off</td>
<td>Off</td>
</tr>
<tr>
<td>VIN &lt; 2V</td>
<td>X</td>
<td></td>
<td>Low</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

X: does not matter  
On: fully turn on  
Off: fully off  
SW: switching

**MP2637A – 2.5A, SINGLE-CELL SW MODE BATTERY CHARGER W/ PPM AND 2.4A BOOST**
ORDERING INFORMATION

<table>
<thead>
<tr>
<th>Part Number*</th>
<th>Package</th>
<th>Top Marking</th>
</tr>
</thead>
<tbody>
<tr>
<td>MP2637AGR</td>
<td>QFN-24 (4mmx4mm)</td>
<td>See Below</td>
</tr>
</tbody>
</table>

* For Tape & Reel, add suffix –Z (e.g. MP2637AGR–Z)

TOP MARKING

MP SYWW
M2637A
LLLLLL

MPS: MPS prefix
Y: Year code
WW: Week code
M2637A: First six digits of the part number
LLLLLL: Lot number

PACKAGE REFERENCE

QFN-24 (4mmx4mm)
ABSOLUTE MAXIMUM RATINGS (1)

- \( V_{\text{VIN}} \) ............................................. -0.3V to 20V
- SYS .................................................. -0.3V to 6.5V
- SW .................................................. 0.3V (-2V for <20ns) to 6.5V (8.5V for <20ns)
- BATT .................................................. -0.3V to 6.5V
- ACOK, CHG, BOOST .............................. -0.3V to 6.5V
- All other pins ...................................... -0.3V to 6.5V
- Junction temperature ............................. 150°C
- Lead temperature ................................. 260°C
- Continuous power dissipation \( (T_A = +25°C) \) (2)
  - Junction temperature ............................. 2.97W
  - Storage temperature ............................. -65°C to +150°C

Recommended Operating Conditions (3)

- Supply voltage \( (V_{\text{VIN}}) \) .................. 4.5V to 6V
- Battery voltage \( (V_{\text{BATT}}) \) .............. 2.5V to 4.35V
- Operating junction temp. \( (T_J) \) ... -40°C to +125°C

The device is not guaranteed to function outside of its operating conditions.

Thermal Resistance (4) \( \theta_{JA} \quad \theta_{JC} \)

- QFN-24 (4mmx4mm) ..................... 42........... 9 .... °C/W

NOTES:

1) Exceeding these ratings may damage the device.
2) The maximum allowable power dissipation is a function of the maximum junction temperature \( T_J \) (MAX), the junction-to-ambient thermal resistance \( \theta_{JA} \), and the ambient temperature \( T_A \). The maximum allowable continuous power dissipation at any ambient temperature is calculated by \( P_{\text{D}}(\text{MAX}) = \frac{(T_J \text{ (MAX)} - T_A)}{\theta_{JA}} \). Exceeding the maximum allowable power dissipation produces an excessive die temperature, causing the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
3) The device is not guaranteed to function outside of its operating conditions.
4) Measured on JESD51-7, 4-layer PCB.
# ELECTRICAL CHARACTERISTICS

$V_{IN} = 5.0V$, $T_A = 25^\circ C$, unless otherwise noted.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Condition</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>IN-to-SYS N-FET on resistance</td>
<td>$R_{IN,\text{SYS}}$</td>
<td>$VCC = 5V$</td>
<td>65</td>
<td>mΩ</td>
<td></td>
<td></td>
</tr>
<tr>
<td>High-side P-FET on resistance</td>
<td>$R_{H,\text{DS}}$</td>
<td>$VCC = 5V$</td>
<td>30</td>
<td>mΩ</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Low-side N-FET on resistance</td>
<td>$R_{L,\text{DS}}$</td>
<td>$VCC = 5V$</td>
<td>30</td>
<td>mΩ</td>
<td></td>
<td></td>
</tr>
<tr>
<td>High-side P-FET peak current limit</td>
<td>$I_{\text{PEAK,HS}}$</td>
<td>CC charge mode/boost mode</td>
<td>6.5</td>
<td>A</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Low-side N-FET peak current limit</td>
<td>$I_{\text{PEAK,LS}}$</td>
<td>TC charge mode</td>
<td>3.2</td>
<td>A</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Switching frequency</td>
<td>$f_{\text{SW}}$</td>
<td></td>
<td>510</td>
<td>620</td>
<td>720</td>
<td>kHz</td>
</tr>
<tr>
<td>VCC UVLO</td>
<td>$V_{\text{CC,UVLO}}$</td>
<td></td>
<td>1.95</td>
<td>2.15</td>
<td>2.35</td>
<td>V</td>
</tr>
<tr>
<td>VCC UVLO hysteresis</td>
<td></td>
<td></td>
<td>100</td>
<td>mV</td>
<td></td>
<td></td>
</tr>
<tr>
<td>PWIN lower threshold</td>
<td>$V_{\text{PWIN,L}}$</td>
<td>Rising</td>
<td>0.72</td>
<td>0.77</td>
<td>0.82</td>
<td>V</td>
</tr>
<tr>
<td>Lower threshold hysteresis</td>
<td></td>
<td></td>
<td>50</td>
<td>mV</td>
<td></td>
<td></td>
</tr>
<tr>
<td>PWIN upper threshold</td>
<td>$V_{\text{PWIN,H}}$</td>
<td>Rising</td>
<td>1.05</td>
<td>1.10</td>
<td>1.15</td>
<td>V</td>
</tr>
<tr>
<td>Upper threshold hysteresis</td>
<td></td>
<td></td>
<td>50</td>
<td>mV</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

## Charge Mode

<table>
<thead>
<tr>
<th>Input quiescent current</th>
<th>$I_{\text{IN}}$</th>
<th>EN = 5V, battery floating</th>
<th>2.5</th>
<th>mA</th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td>EN = 0V</td>
<td>1.5</td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td>Input current limit</td>
<td>$I_{\text{IN,LIMIT}}$</td>
<td>$R_{\text{LIM}} = 100k\Omega$</td>
<td>400</td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>$R_{\text{LIM}} = 56k\Omega$</td>
<td>720</td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>$R_{\text{LIM}} = 16.5k\Omega$</td>
<td>2400</td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td>Input over-current threshold</td>
<td>$I_{\text{IN(OCP)}}$</td>
<td></td>
<td>4.2</td>
<td>A</td>
<td></td>
</tr>
<tr>
<td>Input over-current blanking time</td>
<td>$T_{\text{INOCBLK}}$</td>
<td></td>
<td>120</td>
<td>μs</td>
<td></td>
</tr>
<tr>
<td>Input over-current recover time</td>
<td>$T_{\text{INRECVR}}$</td>
<td></td>
<td>100</td>
<td>ms</td>
<td></td>
</tr>
<tr>
<td>Terminal battery voltage</td>
<td>$V_{\text{BATT,\text{FULL}}}$</td>
<td>Connect VB to GND</td>
<td>4.179</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Leave VB floating or connect to logic high</td>
<td>4.034</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Recharge threshold</td>
<td>$V_{\text{RECH}}$</td>
<td>Connect to VB to GND</td>
<td>3.98</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Leave VB floating or connect to logic high</td>
<td>3.84</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Recharge threshold hysteresis</td>
<td></td>
<td></td>
<td>150</td>
<td>mV</td>
<td></td>
</tr>
<tr>
<td>Battery over-voltage threshold</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Constant charge (CC) current</td>
<td>$I_{\text{CC}}$</td>
<td>As a percentage of $V_{\text{BATT,\text{FULL}}}$</td>
<td>102.5%</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>RS1 = 20mΩ, $R_{\text{ISET}} = 120k\Omega$</td>
<td>850</td>
<td>mA</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>RS1 = 20mΩ, $R_{\text{ISET}} = 60.4k\Omega$</td>
<td>1725</td>
<td>mA</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>RS1 = 20mΩ, $R_{\text{ISET}} = 47.5k\Omega$</td>
<td>2225</td>
<td>mA</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Trickle charge current</td>
<td>$I_{\text{TC}}$</td>
<td></td>
<td>125</td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td>Trickle charge voltage threshold</td>
<td>$V_{\text{BATT,TC}}$</td>
<td>Connect to VB to GND</td>
<td>2.9</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td></td>
<td>Leave VB floating or connect to high logic</td>
<td>2.8</td>
<td>V</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

MP2637A – 2.5A, SINGLE-CELL SW MODE BATTERY CHARGER W/ PPM AND 2.4A BOOST

MP2637A Rev. 1.0

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11/29/2017


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### ELECTRICAL CHARACTERISTICS (continued)

\( V_{IN} = 5.0\, \text{V}, \, T_A = 25^\circ\, \text{C} \), unless otherwise noted.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Condition</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>Trickle charge hysteresis</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Termination charge current</td>
<td>( I_{BF} )</td>
<td>RS1 = 20m\Omega, ( R_{SET} = 60.4, \text{k}\Omega )</td>
<td>2.5%</td>
<td>10%</td>
<td>17.5%</td>
<td>( I_{CC} )</td>
</tr>
<tr>
<td>Input-voltage-regulation reference</td>
<td>( V_{REG} )</td>
<td></td>
<td>1.13</td>
<td>1.15</td>
<td>1.17</td>
<td>V</td>
</tr>
<tr>
<td>Boost Mode</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>SYS voltage range</td>
<td></td>
<td></td>
<td>4.2</td>
<td>6</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Feedback voltage</td>
<td></td>
<td></td>
<td>1.13</td>
<td>1.15</td>
<td>1.17</td>
<td>V</td>
</tr>
<tr>
<td>Feedback input current</td>
<td></td>
<td>( V_{FB} = 1, \text{V} )</td>
<td></td>
<td></td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td>Boost SYS over-voltage protection threshold</td>
<td>( V_{SYS(OVP)} )</td>
<td>Threshold over ( V_{SYS} ) to turn off the converter during boost mode</td>
<td>5.40</td>
<td>5.55</td>
<td>5.70</td>
<td>V</td>
</tr>
<tr>
<td>SYS over-voltage protection threshold hysteresis</td>
<td>( I_{SYS} = 0, \text{A}, , \text{MODE} = 5, \text{V} )</td>
<td>125</td>
<td></td>
<td></td>
<td>mV</td>
<td></td>
</tr>
<tr>
<td>Boost quiescent current</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>Programmable boost output current limit accuracy</td>
<td>( I_{OLIM} )</td>
<td>RS1 = 20m\Omega, ( R_{OLIM} = 57.6, \text{k}\Omega )</td>
<td>1.875</td>
<td>2.083</td>
<td>2.290</td>
<td>A</td>
</tr>
<tr>
<td>SY5 over-current blanking time ((5))</td>
<td>( T_{SYSOCBLK} )</td>
<td></td>
<td>120</td>
<td></td>
<td></td>
<td>( \mu\text{s} )</td>
</tr>
<tr>
<td>SYS over-current recover time ((5))</td>
<td>( T_{SYSRECVR} )</td>
<td></td>
<td>1</td>
<td></td>
<td></td>
<td>ms</td>
</tr>
<tr>
<td>Weak battery threshold</td>
<td>( V_{BATT(LOW)} )</td>
<td>During boosting</td>
<td>2.40</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Sleep Mode</td>
<td></td>
<td>Before boost starts</td>
<td>2.75</td>
<td>2.90</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Battery leakage current</td>
<td>( I_{LEAKAGE} )</td>
<td>( V_{BATT} = 4.2, \text{V}, , \text{SYS floating}, , V_{IN} = 0, \text{V}, , \text{MODE} = 0, \text{V} )</td>
<td>15</td>
<td>30</td>
<td></td>
<td>( \mu\text{A} )</td>
</tr>
</tbody>
</table>

### Indication and Logic

<table>
<thead>
<tr>
<th>ACOK, CHG, BOOST pin output low voltage</th>
<th>Sinking 1.5mA</th>
<th>400</th>
<th>mV</th>
</tr>
</thead>
<tbody>
<tr>
<td>ACOK, CHG, BOOST pin leakage current</td>
<td>Connected to 5V</td>
<td>1</td>
<td>( \mu\text{A} )</td>
</tr>
<tr>
<td>NTC and time-out fault blinking frequency ((5))</td>
<td>( C_{TMR} = 0.1\mu\text{F}, , I_{CHG} = 1, \text{A} )</td>
<td>12.5</td>
<td>Hz</td>
</tr>
<tr>
<td>EN input logic low voltage</td>
<td>0.4</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>EN input high voltage</td>
<td>1.4</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Mode input logic low voltage</td>
<td>0.4</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Mode input logic high voltage</td>
<td>1.4</td>
<td>V</td>
<td></td>
</tr>
</tbody>
</table>
**ELECTRICAL CHARACTERISTICS (continued)**

*V_{IN} = 5.0V, T_A = 25°C, unless otherwise noted.*

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Condition</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>Protection</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Total charge time</td>
<td></td>
<td>$C_{TMR} = 0.1\mu F, I_{CHG} = 1A$</td>
<td>336</td>
<td></td>
<td></td>
<td>min</td>
</tr>
<tr>
<td>NTC low temp, rising threshold</td>
<td>$R_{NTC}$</td>
<td>$NCP18XH103 (0^\circ C)$</td>
<td>66.6%</td>
<td>66.6%</td>
<td>67.6%</td>
<td>V_{SYS}</td>
</tr>
<tr>
<td>NTC low temp, rising threshold hysteresis</td>
<td>$R_{NTC}$</td>
<td>$NCP18XH103 (50^\circ C)$</td>
<td>1.0%</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>NTC high temp, rising threshold</td>
<td></td>
<td>$R_{NTC} = NCP18XH103 (0^\circ C)$</td>
<td>34%</td>
<td>35%</td>
<td>36%</td>
<td></td>
</tr>
<tr>
<td>NTC high temp, rising threshold hysteresis</td>
<td>$R_{NTC}$</td>
<td>$NCP18XH103 (50^\circ C)$</td>
<td>1.0%</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Charging current foldback threshold</td>
<td></td>
<td>$\text{Charge mode}$</td>
<td>120</td>
<td></td>
<td></td>
<td>°C</td>
</tr>
<tr>
<td>(5)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Thermal shutdown threshold</td>
<td></td>
<td></td>
<td>150</td>
<td></td>
<td></td>
<td>°C</td>
</tr>
</tbody>
</table>

**NOTES:**

5) Guaranteed by design.
TYPICAL CHARACTERISTICS

$C_{IN} = C_{BATT} = C_{SYS} = C_2 = 22\mu F$, $L_1 = 2.2\mu H$, $R_{S1} = 20m\Omega$, $C_4 = C_{TMR} = 0.1\mu F$, battery simulator, unless otherwise noted.

$V_{BATT\_FULL}$ vs. Temperature

$V_{BATT\_FULL} = 4.055V (V_B = V_{CC})$

$V_{BATT\_OVP}$ vs. Temperature

$V_{BATT\_FULL} = 4.055V (V_B = V_{CC})$

$V_{BATT\_FULL}$ vs. Temperature

$V_{BATT\_FULL} = 4.200V (V_B = GND)$

$V_{BATT\_FULL}$ vs. Temperature

$V_{BATT\_FULL} = 4.200V (V_B = GND)$

$BATT_{OVP\_VBL}$ vs. Temperature

$V_{BATT\_FULL} = 4.200V (V_B = GND)$

$CC$ Charge Current vs. Temperature

$R_{SET} = 47.5k\Omega$

$BATT\_LKG$ vs. Temperature

$R_{OLIM} = 51k\Omega$

$Output\_Current\_Limit$ vs. Temperature

$FB\_Voltage$ vs. Temperature

$SYS\_OVP$ vs. Temperature

unless otherwise noted.
TYPICAL PERFORMANCE CHARACTERISTICS
For Charge Mode: $V_{IN} = 5V$, $I_{CHG} = 2.5A$, $L_{IN\_LIM} = 2.7A$, $I_{SYS} = 0A$
For Boost Mode: $V_{BATT} = 3.7V$, $V_{SYS\_SET} = 5V$, $I_{OLIM} = 2.1A$
$C_{IN} = C_{BATT} = C_{SYS} = C_{2} = 22\mu F$, $L_{1} = 2.2\mu H$, $R_{S1} = 20m\Omega$, $C_{4} = C_{TMR} = 0.1\mu F$, battery simulator, unless otherwise noted.

**Battery Charge Curve**

**Auto Recharge**

**Battery Float Steady State**

**TC Charge Steady State**

**CC Charge Steady State**

**CV Charge Steady State**

**Constant Current Charge Efficiency**

**Constant Voltage Charge Efficiency**
TYPICAL PERFORMANCE CHARACTERISTICS (continued)
For Charge Mode: $V_{IN} = 5V$, $I_{CHG} = 2.5A$, $I_{IN,LIM} = 2.7A$, $I_{SYS} = 0A$
For Boost Mode: $V_{BATT} = 3.7V$, $V_{SYS,SET} = 5V$, $I_{OLIM} = 2.1A$
$C_{IN} = C_{BATT} = C_{SYS} = C2 = 22\mu F$, $L1 = 2.2\mu H$, $RS1 = 20m\Omega$, $C4 = C_{TMR} = 0.1\mu F$, battery simulator, unless otherwise noted.

**Power On, Charger Mode**
$V_{BATT, FULL} = 4.2V$, $V_{BATT} = 3.7V$, $I_{CHG} = 2.5A$

**Power Off, Charger Mode**
$V_{BATT, FULL} = 4.2V$, $V_{BATT} = 3.7V$, $I_{CHG} = 2.5A$

**EN On, Charge Mode**
$V_{BATT, FULL} = 4.2V$, $V_{BATT} = 3.7V$, $I_{CHG} = 2.5A$

**EN Off, Charge Mode**
$V_{BATT, FULL} = 4.2V$, $V_{BATT} = 3.7V$?? $I_{CHG} = 2.5A$

**Input Current Limit, Charge Mode**
$V_{BATT, FULL} = 4.2V$, $V_{BATT} = 3.7V$

**Input Voltage Clamp, Charge Mode**
$V_{BATT, FULL} = 4.2V$, $V_{BATT} = 3.7V$

**Input Over-Voltage Protection, Charge Mode**
$V_{IN} = 5V$ to 6.5V, $V_{BATT} = 3.7V$, Enabled Charger
TYPICAL PERFORMANCE CHARACTERISTICS (continued)
For Charge Mode: $V_{IN} = 5V$, $I_{CHG} = 2.5A$, $L_{IN\_LIM} = 2.7A$, $I_{SYS} = 0A$
For Boost Mode: $V_{BATT} = 3.7V$, $V_{SYS\_SET} = 5V$, $I_{OLIM} = 2.1A$
$C_{IN} = C_{BATT} = C_{SYS} = C_{2} = 22\mu F$, $L_1 = 2.2\mu H$, $R_{S1} = 20m\Omega$, $C_{4} = C_{TMR} = 0.1\mu F$, battery simulator, unless otherwise noted.

Power On, Boost Mode
$V_{SYS\_SET}=5V$, $V_{BATT}=3.7V$, No SYS Load

Power Off, Boost Mode
$V_{SYS\_SET}=5V$, $V_{BATT}=3.7V$, No SYS Load

Power On, Boost Mode
$V_{SYS\_SET}=5V$, $V_{BATT}=3.7V$, No SYS Load

Power Off, Boost Mode
$V_{SYS\_SET}=5V$, $V_{BATT}=3.7V$, $R_{SYS\_LOAD}=2.5\Omega$

Mode On, Boost Mode
$V_{SYS\_SET}=5V$, $V_{BATT}=3.7V$, No SYS Load

Mode Off, Boost Mode
$V_{SYS\_SET}=5V$, $V_{BATT}=3.7V$, $R_{SYS\_LOAD}=2\Omega$

Mode On, Boost Mode
$V_{SYS\_SET}=5V$, $V_{BATT}=3.7V$, $R_{SYS\_LOAD}=2\Omega$

Mode Off, Boost Mode
$V_{SYS\_SET}=5V$, $V_{BATT}=3.7V$, $R_{SYS\_LOAD}=2\Omega$

SYS Output Current Limit
$V_{SYS\_SET}=5V$, $V_{BATT}=3.7V$, $I_{OLIM\_SET}=2.5A$
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

For Charge Mode: $V_{IN} = 5V$, $I_{CHG} = 2.5A$, $L_{IN\_LIM} = 2.7A$, $I_{SYS} = 0A$

For Boost Mode: $V_{BATT} = 3.7V$, $V_{SYS\_SET} = 5V$, $I_{OLIM} = 2.1A$

$C_{IN} = C_{BATT} = C_{SYS} = C2 = 22\mu F$, $L1 = 2.2\mu H$, $RS1 = 20m\Omega$, $C4 = C_{TMR} = 0.1\mu F$, battery simulator, unless otherwise noted.

### SYS Load Transient

- **SYS Load Transient**
  - $V_{SYS\_SET} = 5V$, $V_{BATT} = 3.7V$
  - $I_{SYS} = 80mA$ to $1A$

- **SYS Load Transient**
  - $V_{SYS\_SET} = 5V$, $V_{BATT} = 3.7V$
  - $I_{SYS} = 1A$ to $2.2A$

- **SYS Load Transient**
  - $V_{SYS\_SET} = 5V$, $V_{BATT} = 3.7V$
  - $I_{SYS} = 0.3A$ to $2.2A$

### Efficiency

- **Efficiency**
  - $V_{SYS\_SET} = 5V$, $V_{SYS} = 5V$, $F_S = 600kHz$

### Boost Output V-I Curve

- **Boost Output V-I Curve**
  - $V_{BATT} = 3.7V$, $V_{SYS} = 5V$

### Programmable Output Current Limit vs. Battery

- **Programmable Output Current Limit vs. Battery**
  - $R_{OLIM} = 59k\Omega$, $V_{SYS} = 5V$
## PIN FUNCTIONS

<table>
<thead>
<tr>
<th>Pin #</th>
<th>Name</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>1, 23, 24</td>
<td>PGND</td>
<td>Power ground.</td>
</tr>
<tr>
<td>2</td>
<td>CHG</td>
<td>Charge completion indicator. CHG at logic low indicates charge mode. CHG is an open-drain pin when the charge is complete or suspended.</td>
</tr>
<tr>
<td>3</td>
<td>BOOST</td>
<td>Boost mode indicator. BOOST at logic low indicates boost mode. BOOST is an open-drain pin during charge mode or sleep mode operation.</td>
</tr>
<tr>
<td>4</td>
<td>CSP</td>
<td>Battery charge current sense positive input.</td>
</tr>
<tr>
<td>5</td>
<td>BATT</td>
<td>Positive battery terminal/battery charge current sense negative input.</td>
</tr>
<tr>
<td>6</td>
<td>AGND</td>
<td>Analog ground.</td>
</tr>
<tr>
<td>7</td>
<td>OLIM</td>
<td>Programmable output current limit for boost mode. Connect an external resistor to GND to program the system current in boost mode. ( R_{\text{OLIM}} ) cannot be lower than 47.5kΩ.</td>
</tr>
<tr>
<td>8</td>
<td>ISET</td>
<td>Programmable charge current. Connect an external resistor from ISET to GND to program the charge current.</td>
</tr>
<tr>
<td>9</td>
<td>NTC</td>
<td>Negative temperature coefficient (NTC) thermistor.</td>
</tr>
<tr>
<td>10</td>
<td>FB</td>
<td>System voltage feedback input.</td>
</tr>
<tr>
<td>11</td>
<td>ACOK</td>
<td>Valid input supply indicator. ACOK at logic low indicates the presence of a valid power supply.</td>
</tr>
<tr>
<td>12</td>
<td>REG</td>
<td>Input voltage feedback for the input voltage regulation loop. Connect REG to the tap of an external resistor divider from VIN to GND to program the input voltage regulation. Once the voltage at REG drops to the inner threshold, the charge current is reduced to maintain the input voltage at the regulation value.</td>
</tr>
<tr>
<td>13</td>
<td>TMR</td>
<td>Oscillator period timer. Connect a timing capacitor between TMR and GND to set the oscillator period. Short TMR to GND to disable the timer function.</td>
</tr>
<tr>
<td>14</td>
<td>PWIN</td>
<td>Input pin to detect the presence of valid input power. Pull PWIN to GND to turn off the IN-to-SYS pass-through FET.</td>
</tr>
<tr>
<td>15</td>
<td>ILIM</td>
<td>Input current set. Connect ILIM to GND with an external resistor to program the input current limit in charge mode.</td>
</tr>
<tr>
<td>16</td>
<td>VCC</td>
<td>Internal circuit power supply. Bypass VCC to GND with a ceramic capacitor no higher than 100nF. VCC cannot carry an external load higher than 5mA.</td>
</tr>
<tr>
<td>17</td>
<td>VB</td>
<td>Programmable battery-full voltage. Leave VB floating or connect VB to logic high for 4.2V. Connect VB to GND for 4.35V.</td>
</tr>
<tr>
<td>18</td>
<td>EN</td>
<td>Charge control input. EN at logic high enables charging. EN at logic low disables charging. EN is active only when ACOK is low (input power is OK).</td>
</tr>
<tr>
<td>19</td>
<td>MODE</td>
<td>Mode selection. Set MODE to logic high to operate the device in boost mode. Set MODE to logic low to operate the device in sleep mode. MODE is active only when ACOK is high (input power is not available).</td>
</tr>
<tr>
<td>20</td>
<td>VIN</td>
<td>Adapter input. Place a bypass capacitor close to VIN to prevent large input voltage spikes.</td>
</tr>
<tr>
<td>21</td>
<td>SYS</td>
<td>System output. A minimum 22μF ceramic capacitor is required to be placed as close to SYS and PGND as possible. The total capacitance should not be lower than 44μF.</td>
</tr>
<tr>
<td>22</td>
<td>SW</td>
<td>Switch output node. Do not to place vias on the SW plane during PCB layout.</td>
</tr>
</tbody>
</table>
Figure 1: Functional Block Diagram in Charge Mode
Figure 2: Functional Block Diagram in Boost Mode
Figure 3: Mode Selection Flow Chart
OPERATION FLOW CHART (continued)

Normal Operation

Charge Mode /CHG Low

Charge Mode?

$V_{BATT} > V_{BATT_{FULL}}$

C.V.C

Yes

Battery Full

No

$V_{BATT} < V_{BATT} - TC$

$V_{BATT} < V_{BATT_{FULL}}$

$V_{BATT} < V_{BATT_{TC}}$

Charge Recovery, Return to Normal Operation

Fault Protection

Timer Out?

Yes

NTC Fault?

Yes

$T_J \geq 120^\circ C$?

Yes

Decrease $I_{CHG}$ to maintain $T_J$ at 120$^\circ$C

No

$T_J \geq 150^\circ C$?

Yes

Charge Termination, /CHG is high

No

Reset Timer?

Yes

NTC OK?

Yes

$T_J \leq 120^\circ C$?

Yes

Thermal Shutdown, /CHG is high

No

Charge Suspend, /CHG is high

Figure 4: Normal Operation and Fault Protection in Charge Mode
Figure 5: Power-Path Management in Charge Mode
OPERATION FLOW CHART (continued)

Boost Mode /BOOST Low

- \( V_{\text{BATT}}>2.9\,\text{V} \) ?
  - Yes
  - Mode High?
    - Yes
    - Normal Boost Operation
    - \( V_{\text{BATT}}<2.5\,\text{V} \) ?
      - Yes
      - Boost Turns Off
    - No
  - No

Normal Boost Operation

- \( I_{\text{SYS}}>I_{\text{OLIM}} \) ?
  - Yes
  - Output current loop works, \( V_{\text{SYS}} \) decreases
    - \( V_{\text{SYS}}<V_{\text{BATT}} \) ?
      - Yes
      - \( V_{\text{SYS}}<2\,\text{V} \) ?
        - Yes
        - Down mode
        - \( T_{\text{SYSBLK}} \) Reaches?
          - Yes
          - Boost Shutdown
          - \( T_{\text{ENSGRECVR}} \) Reaches?
            - Yes
            - No
        - No
      - Yes
      - No
    - No
  - No

Figure 6: Operation Flow Chart in Boost Mode
START-UP TIME FLOW IN CHARGE MODE
Condition: EN = 5V, MODE = 0V, ACOK and CHG are always pulled up to an external 5V.

Figure 7: Input Power Start-Up Time Flow in Charge Mode
START-UP TIME FLOW IN CHARGE MODE (continued)

Condition: \( EN = 5V \), \( MODE = 0V \), \( \text{ACOK} \) and \( \text{CHG} \) are always pulled up to an external 5V.

Figure 8: EN Start-Up Time Flow in Charge Mode
START-UP TIME FLOW IN BOOST MODE (continued)

Condition: $V_{IN} = 0V$, Mode = 5V, BOOST is always pulled up to an external constant 5V.

Figure 9: Battery Power Start-Up Time Flow in Boost Mode
START-UP TIME FLOW IN BOOST MODE \textit{(continued)}

Condition: $V_{IN} = 0V$, BOOST is always pulled up to an external constant 5V.

![Diagram](image)

Figure 10: Mode Start-Up Time Flow in Boost Mode
OPERATION

The MP2637A is a highly-integrated, flexible, switch-mode battery charger with system power path management designed for single-cell Li-ion or Li-polymer batteries for use in a wide range of applications. Depending on the status of the input, the MP2637A can operate in three different modes: charge mode, boost mode, or sleep mode.

In charge mode, the MP2637A can work with a single cell Li-ion or Li-polymer battery. In boost mode, the MP2637A boosts the battery voltage to \( V_{SYS\_SET} \) to power higher voltage system rails. In sleep mode, both charging and boost operations are disabled and the device enters power-saving mode to help reduce the overall power consumption. The MP2637A monitors \( V_{IN} \) to allow for a smooth transition between different modes of operation.

CHARGE MODE OPERATION

Charge Cycle (Trickle Charge \( \rightarrow \) CC Charge \( \rightarrow \) CV Charge)

In charge mode, the MP2637A has five control loops to regulate the input current, input voltage, charge current, charge voltage, and device junction temperature. The MP2637A charges the battery in three phases: trickle current (TC), constant current (CC), and constant voltage (CV). While charge operation is enabled, all five loops are active, but only one determines the IC behavior. A typical battery charge profile is shown in Figure 11a. The charger remains in TC charge mode until the battery voltage reaches the TC-to-CC threshold. Otherwise, the charger enters CC charge mode. When the battery voltage rises to the CV mode threshold, the charger operates in CV mode. Figure 11b shows a typical charge profile when the input current limit loop dominates during CC charge mode. In this case, the charger maximizes the charging current due to the switching mode charging solution, resulting in faster charging than a traditional linear solution.

Auto-Recharge

Once the battery charge cycle is completed, the charger remains off. During this time, the system load may consume battery power, or the battery may self-discharge. To ensure that the battery will not deplete, a new charge cycle begins automatically when the battery voltage falls below the auto-recharge threshold and the input power is present. The timer is reset when the auto-recharge cycle begins.

During the off state after the battery is fully charged, if the input power restarts or the EN signal refreshes, the charge cycle starts, and the timer resets, regardless of the battery voltage.

Battery Over-Voltage Protection (OVP)

The MP2637A has battery over-voltage protection (OVP). If the battery voltage exceeds the battery over-voltage threshold, (102.5% of the battery-full voltage), charging is disabled. Under this condition, an internal 5kΩ dummy load draws a current from BATT to decrease the battery voltage and protect the battery.
Timer Operation in Charge Mode
The MP2637A uses an internal timer to terminate the charging. The timer remains active during the charging process. An external capacitor between TMR and GND programs the charge cycle duration. The total charge time can be calculated with Equation (1):

\[
\tau_{TOTAL,TMR} = \frac{3.4 \times 10^6 \times 1.6(V) \times C_{TMR}(\mu F)}{1.25 \times I_{CHG}(A) \times R\text{S}(m\Omega) + 2(\mu A)} (s) (1)
\]

Negative Temperature Coefficient (NTC) Input for Battery Temperature Monitoring
The MP2637A has a built-in NTC resistance window comparator which allows the MP2637A to monitor the battery temperature via the battery-integrated thermistor. Connect an appropriate resistor from V_SYS to the NTC pin, and connect the thermistor from the NTC pin to GND. The resistor divider determines the NTC voltage depending on the battery temperature. If the NTC voltage falls outside of the NTC window, the MP2637A stops charging. The charger restarts if the temperature goes back into NTC window range. Please refer to Application Information section on page 30 for the appropriate resistance selection.

Input Current Limiting in Charge Mode (ILIM)
The MP2637A has a dedicated pin (ILIM) used to program the input current limit. The current at ILIM is a fraction of the input current. The voltage at ILIM indicates the average input current of the switching regulator as determined by the resistor value between ILIM and GND. As the input current approaches the programmed input current limit, the charge current is reduced to give priority to the system power. Determine the input current-limit threshold with Equation (2):

\[
I_{LIM} = \frac{45(k\Omega)}{R_{LIM}(k\Omega)} (A) (2)
\]

Input Voltage Regulation in Charge Mode
In charge mode, if the input power source is not sufficient enough to support both the charge current and system load current, the input voltage decreases. As the input voltage approaches the programmed input voltage regulation value, the charge current is reduced to give priority to the system power and maintain proper regulation of the input voltage. The input voltage can be regulated by a resistor divider from VIN to REG to AGND, according to Equation (3):

\[
V_{REG} = \frac{V_{IN,R} \times R5}{R3 + R5} (V) (3)
\]

Where \( V_{REG} \) is the internal voltage reference (1.15V), and \( V_{IN,R} \) is the desired regulation voltage.

Integrated Over-Current Protection (OCP) and Over-Voltage Protection (OVP) for Pass-Through Path
The MP2637A has an integrated IN-to-SYS pass-through path to allow for direct connection of the input voltage to the system, even if charging is disabled. The MP2637A monitors both the input current and voltage continuously. In the event of over-load, the charge current is reduced to ensure priority of the system power requirements.

Additionally, the MP2637A also features input over-current and over-voltage protection for the IN-to-SYS pass-through path.

Input Over-Current Protection (OCP)
If the total input current exceeds 4.2A, Q2 is controlled linearly to regulate the current (see Figure 12). If the current continues to exceed 4.2A after 120\( \mu \)s of blanking time, Q2 is turned off. If the input current exceeds 7A, Q2 is turned off almost instantaneously and without any blanking time to protect both Q1 and Q2.

Input Over-Voltage Protection (OVP)
The MP2637A uses the PWIN pin to sense the status of the input voltage. When the voltage at PWIN is lower than 0.77V or higher than 1.10V, an invalid input power source is detected by the MP2637A. At this time, the IN-to-SYS pass-through path is turned off. An OVP threshold can be programmed via PWIN to prevent an over-voltage event from occurring on the SYS side when plugging in an incorrect adapter.
Non-Sync Operation Mode

During charging mode, the MP2637A monitors the total input current flowing from IN to SYS continuously. When the input current is lower than 170mA, the low-side switch operates as a non-synchronous FET.

Constant-Off-Time Control for Large Duty Charging Operation

The MP2637A has a built-in 600kHz frequency oscillator for the switching frequency. Unlike a traditional fixed frequency, the MP2637A features a constant-off-time control to support the constant-current charge, even when the input voltage is very close to the battery voltage. The MP2637A compares the high-side FET sense current with comp level continuously (see Figure 13). If the sense current does not reach the comp level within the original switching period, the next clock is delayed until the sense current reaches the comp level. As a result, the duty cycle is able to be extended as large as possible.

Full Operation Indication

The MP2637A integrates indicators for the following conditions shown in Table 2.

The blinking frequency can be calculated with Equation (5):

\[ F_{\text{Blinking}} = \frac{1(\mu A)}{0.8 \times C_{\text{TMR}}(\mu F)} \]  

Table 2: Indicator for Each Operation Mode

<table>
<thead>
<tr>
<th>Operation</th>
<th>ACOK</th>
<th>CHG</th>
<th>BOOST</th>
</tr>
</thead>
<tbody>
<tr>
<td>Charge mode</td>
<td>In Charging</td>
<td>Low</td>
<td></td>
</tr>
<tr>
<td></td>
<td>End of charge, charging disabled, battery OVP</td>
<td>High</td>
<td>High</td>
</tr>
<tr>
<td></td>
<td>NTC fault, timer out</td>
<td>Blinking</td>
<td></td>
</tr>
<tr>
<td>Boost mode</td>
<td>High</td>
<td>High</td>
<td>Low</td>
</tr>
<tr>
<td>Sleep mode</td>
<td>High</td>
<td>High</td>
<td>High</td>
</tr>
</tbody>
</table>
Boost Mode Operation
Low-Voltage Start-Up
The minimum battery voltage required to start up the circuit in boost mode is 2.75V. Initially, when \( V_{SYS} \) is less than \( V_{BATT} \), the MP2637A works in down mode. In this mode, the synchronous P-channel FET (P-FET) stops switching, and its gate connects to \( V_{BATT} \) statically. The P-FET stays off as long as the voltage across the parasitic \( C_{DS} \) (\( V_{SW} \)) is lower than \( V_{BATT} \). When the voltage across \( C_{DS} \) exceeds \( V_{BATT} \), the synchronous P-FET enters linear mode, allowing the inductor current to decrease and flow into SYS. Once \( V_{SYS} \) exceeds \( V_{BATT} \), the P-FET gate is released, and normal closed-loop pulse-width modulation (PWM) operation is initiated. In boost mode, the battery voltage can drop as low as 2.40V without affecting circuit operation.

SYS Disconnect and Inrush Limiting
The MP2637A allows for true output disconnect by eliminating body diode conduction of the internal P-FET rectifier. \( V_{SYS} \) can drop to 0V during shutdown, drawing no current from the input source. The MP2637A also allows for inrush current limiting at start-up, minimizing surge currents from the input supply. To optimize the benefits of the output disconnect, avoid connecting an external Schottky diode between SW and SYS.

Board layout is extremely critical for minimizing voltage overshoot at SW due to stray inductance. Keep the output filter capacitor as close as possible to SYS and use very low ESR/ESL ceramic capacitors tied to a good ground plane.

Boost Output Voltage Setting
In boost mode, the MP2637A programs the output voltage via the external resistor divider at FB and provides built-in output OVP to protect the device and other components against damage when \( V_{SYS} \) goes beyond 5.55V. Once output over-voltage occurs, the MP2637A turns off the boost converter. When the voltage on \( V_{SYS} \) drops to a normal level, the boost converter restarts as long as MODE remains in active status.

Boost Output Current Limiting
The MP2637A integrates a programmable output current limit function in boost mode. If the boost output current exceeds this programmable limit, the output current is limited at this level, and the SYS voltage starts to drop down. \( OLIM \) programs the current limit threshold up to 2.4A per Equation (6):

\[
I_{OLIM}(A) = \frac{2400}{R_{OLIM}(\Omega) \times R_{S1}(m\Omega)}
\]  

SYS Output Over-Current Protection (OCP)
The MP2637A integrates three-phase output OCP.

1. Phase one (boost mode output current limit): When the output current exceeds the programmed output current limit, the output constant current loop controls the output current, the output current remains at its limit of \( I_{OLIM} \), and \( V_{SYS} \) decreases.
2. **Phase two (down mode):** When \( V_{SYS} \) drops below \( V_{BATT} + 100\text{mV} \) and the output current loop remains in control, the boost converter enters down mode and shuts down after 120\(\mu\text{s} \) of blanking time.

3. **Phase three (short-circuit mode):** When \( V_{SYS} \) drops below 3.75V (2V during boost soft start), the boost converter shuts down immediately once the inductor current reaches the foldback peak current limit of the low-side N-channel FET (N-FET). The boost converter can also recover automatically after a 1ms deglitch period.

**Thermal Shutdown Protection**

Thermal shutdown protection is also active in boost mode. Once the junction temperature rises higher than 150°C, the MP2637A enters thermal shutdown. The MP2637A does not resume normal operation until the junction temperature drops below 120°C.
APPLICATION INFORMATION

Setting the Charge Current in Charge Mode

In charge mode, both the external sense resistor (RS1) and RSET connect to ISET to set the charge current (ICHG) of the MP2637A. Given ICHG and RS1, RSET can be calculated with Equation (7):

\[ R_{\text{SET}}(\Omega) = \frac{2400}{I_{\text{CHG}}(A) \times R_S(\text{m}\Omega)} \] (7)

For example, if ICHG = 2.5A, and RS1 = 20mΩ, then RSET = 48kΩ.

Setting the Input Current Limiting in Charge Mode

In charge mode, connect a resistor from ILIM to AGND to program the input current limit. The relationship between the input current limit and setting resistor is shown in Equation (8):

\[ R_{\text{ILIM}} = \frac{45}{I_{\text{IN_LIM}}(A)}(\text{k}\Omega) \] (8)

Where RILIM must exceed 16.5kΩ so that IN_LIM is in the range of 0A to 2.7A.

For most applications, use RILIM = 50kΩ (IUSB_LIM = 900mA) for USB 3.0 mode, and use RILIM = 90kΩ (IUSB_LIM = 500mA) for USB 2.0 mode.

Setting the Input Voltage Range for Different Operation Modes

A resistive voltage divider from the input to PWIN determines the operating mode of MP2637A and can be calculated with Equation (9):

\[ V_{\text{PWIN}} = V_{\text{IN}} \times \frac{R_6}{R_4 + R_6} \text{(V)} \] (9)

If the voltage on PWIN is between 0.77V and 1.10V, the MP2637A works in charge mode. When the voltage on PWIN is outside the range of 0.77V to 1.10V and VIN > 2V, the MP2637A works in boost mode (see Table 1).

For a wide operating range, use a maximum input voltage of 5.74V as the upper threshold for a voltage ratio shown in Equation (10):

\[ \frac{V_{\text{PWIN}}}{V_{\text{IN}}} = \frac{1.10}{5.74} = \frac{R_6}{R_4 + R_6} \] (10)

With the given R6, R4 can then be calculated with Equation (11):

\[ R_4 = \frac{V_{\text{IN}} - V_{\text{PWIN}}}{V_{\text{PWIN}}} \times R_6 \] (11)

For a typical application, start with R6 = 5.1kΩ. R4 is then 21.5kΩ.

Setting the Input Voltage Regulation in Charge Mode

In charge mode, connect a resistor divider from VIN to AGND tapped to REG to program the input voltage regulation. Calculate VIN_R with Equation (12):

\[ V_{\text{IN,R}} = V_{\text{REG}} \times \frac{R_3 + R_5}{R_5} \text{(V)} \] (12)

With a given R5, R3 can then be calculated with Equation (13):

\[ R_3 = \frac{V_{\text{IN,R}} - V_{\text{REG}}}{V_{\text{REG}}} \times R_5 \text{(V)} \] (13)

For a preset input voltage regulation value (i.e.: 4.75V), start with R5 = 5.1kΩ. R3 is then 15.8kΩ.

NTC Function in Charge Mode

Figure 14 shows that an internal resistor divider sets the low temperature threshold (VTL) and high temperature threshold (VTH) at 66.6% · VSYS and 35% · VSYS, respectively.
For a given NTC thermistor, select an appropriate \( R_{T1} \) and \( R_{T2} \) to set the NTC window with Equation (14) and Equation (15):

\[
\frac{V_{TL}}{V_{SYS}} = \frac{R_{T2}/R_{NTC\_Cold}}{R_{T1} + R_{T2}/R_{NTC\_Cold}} = TL = 66.6\% \quad (14)
\]

\[
\frac{V_{TH}}{V_{SYS}} = \frac{R_{T2}/R_{NTC\_Hot}}{R_{T1} + R_{T2}/R_{NTC\_Hot}} = TH = 35\% \quad (15)
\]

Where \( R_{NTC\_Hot} \) is the value of the NTC resistor at the upper bound of its operating temperature range, and \( R_{NTC\_Cold} \) is its lower bound.

The two resistors, \( R_{T1} \) and \( R_{T2} \), determine the upper and lower temperature limits independently. This flexibility allows the MP2637A to operate with most NTC resistors for different temperature range requirements.

Calculate \( R_{T1} \) and \( R_{T2} \) with Equation (16) and Equation (17):

\[
R_{T1} = \frac{R_{NTC\_Hot} \times R_{NTC\_Cold} \times (TL - TH)}{TH \times TL \times (R_{NTC\_Cold} - R_{NTC\_Hot})} \quad (16)
\]

\[
R_{T2} = \frac{(TL - TH) \times R_{NTC\_Cold} \times R_{NTC\_Hot}}{(1 - TL) \times TH \times R_{NTC\_Cold} \times (1 - TH) \times TL \times R_{NTC\_Hot}} \quad (17)
\]

For example, the NCP18XH103 thermistor has the following electrical characteristics:

- At 0°C, \( R_{NTC\_Cold} = 27.445k\Omega \)
- At 50°C, \( R_{NTC\_Hot} = 4.1601k\Omega \).

Based on Equation (16) and Equation (17), \( R_{T1} = 6.65k\Omega \) and \( R_{T2} = 25.63k\Omega \) are suitable for an NTC window between 0°C and 50°C. Chose approximate values (e.g. \( R_{T1} = 6.65k\Omega \) and \( R_{T2} = 25.5k\Omega \)).

If no external NTC is available, connect \( R_{T1} \) and \( R_{T2} \) to keep the voltage on NTC within the valid NTC window (e.g.: \( R_{T1} = R_{T2} = 10k\Omega \)).

For convenience, an NTC thermistor design spreadsheet has been provided.

**Setting the System Voltage in Boost Mode**

In boost mode, the system voltage can be regulated to the customer-required value between 4.2V to 6V by the resistor divider at FB. Calculate \( V_{SYS} \) with Equation (18):

\[
V_{SYS} = 1.15 \times \frac{R1 + R2}{R2} \quad (18)
\]

Where 1.15V is the voltage reference of SYS. With a typical value for \( R2 \) (10k\Ω), \( R1 \) can be determined with Equation (19):

\[
R1 = R2 \times \frac{V_{SYS} - 1.15}{1.15} \quad (19)
\]

For example, for a 5V system voltage, \( R2 \) is 10k\Ω, and \( R1 \) is 33k\Ω.

**Setting the Output Current Limit in Boost Mode**

In boost mode, connect a resistor from OLIM to AGND to program the output current limit. The relationship between the output current limit and setting resistor is shown in Equation (20):

\[
I_{OLIM}(A) = \frac{2400}{R_{OLIM}(k\Omega) \times R_{S1}(m\Omega)} \quad (20)
\]

The output current limit of the boost can be programmed up to 2.1A (min). Considering a 10% output current limit accuracy, a 2.3A output current limit is required, typically. According to Equation (20), given a 20m\Ω sense resistor, a 52k\Ω \( R_{OLIM} \) can achieve a 2.3A output current limit.

For safe operation, \( R_{OLIM} \) cannot be lower than 47.5k\Ω.

**Selecting the Inductor**

Inductor selection is a trade-off between cost, size, and efficiency. A lower inductance value results in a smaller size but also has higher current ripple, higher magnetic hysteretic losses, and higher output capacitances. However, a higher inductance value results in lower ripple current and smaller output filter capacitors but also has higher inductor DC resistance (DCR) loss. Choose an inductor that does not saturate under the worst-case load condition.

1. **Selecting an Inductor in Charge Mode**

When the MP2637A works in charge mode (as a buck converter), estimate the required inductance with Equation (21):

\[
L = \frac{V_{IN} - V_{BATT}}{\Delta L_{MAX}} \times \frac{V_{BATT}}{V_{IN} \times f_{SW}} \quad (21)
\]
Where $V_{IN}$ is the typical input voltage, $V_{BATT}$ is the typical CC charge threshold, $f_s$ is the typical switching frequency, and $\Delta I_{L\_MAX}$ is the maximum peak-to-peak inductor current (usually designed at 30 - 40% of the CC charge current).

With a typical 5V input voltage, a 35% inductor current ripple at the corner point between the trickle charge and CC charge ($V_{BATT} = 3V$, $I_{chg} = 2.5A$), the inductance $2.2\mu H$.

2. **Selecting an Inductor in Boost Mode**

When the MP2637A is in boost mode (as a boost converter), the required inductance value can be calculated with Equation (22), Equation (23), and Equation (24):

$$L = \frac{V_{BATT} \times (V_{SYS} - V_{BATT})}{V_{SYS} \times f_s \times \Delta I_{L\_MAX}}$$  

(22)

$$\Delta I_{L\_MAX} = (30\% - 40\%) \times I_{BATT(MAX)}$$  

(23)

$$I_{BATT(MAX)} = \frac{V_{SYS} \times I_{SYS}}{V_{BATT} \times \eta}$$  

(24)

Where $V_{BATT}$ is the minimum battery voltage, $f_s$ is the switching frequency, and $\Delta I_{L\_MAX}$ is the peak-to-peak inductor ripple current (approximately 30% of the maximum battery current $I_{BATT(MAX)}$), $I_{SYS(MAX)}$ is the system current, and $\eta$ is the efficiency.

In the worst-case scenario where the battery voltage is 3V, a 30% inductor current ripple, and a typical system voltage ($V_{SYS} = 5V$), the inductance is $1.5\mu H$ when the efficiency is 90%.

For best results, use an inductor with an inductance of $2.2\mu H$ and a DC current rating no lower than the peak current of the FET. For higher efficiency, minimize the inductor’s DC resistance.

**Selecting the Input Capacitor (C_IN)**

The input capacitor ($C_{IN}$) reduces both the surge current drawn from the input and the switching noise from the device. The input capacitor impedance at the switching frequency should be less than the input source impedance to prevent high-frequency switching current from passing to the input. For best results, ceramic capacitors with X7R dielectrics are recommended for their low ESR and small temperature coefficients. For most applications, a $22\mu F$ capacitor is sufficient.

**Selecting the System Capacitor (C_SYS)**

Select $C_{SYS}$ based on the demand of the system current ripple.

1. **Selecting a System Cap in Charge Mode**

$C_{SYS}$ acts as the input capacitor of the boost converter in charge mode. The input current ripple can be calculated with Equation (25):

$$I_{RMS\_MAX} = I_{SYS\_MAX} \times \sqrt{\frac{V_{TC} \times (V_{IN\_MAX} - V_{TC})}{V_{IN\_MAX}}}$$  

(25)

2. **Selecting a System Cap in Boost Mode**

$C_{SYS}$ is the output capacitor of boost converter. $C_{SYS}$ keeps the system voltage ripple small and ensures feedback loop stability. The system current ripple is given by Equation (26):

$$I_{RMS\_MAX} = I_{SYS\_MAX} \times \sqrt{\frac{V_{TC} \times (V_{SYS\_MAX} - V_{TC})}{V_{SYS\_MAX}}}$$  

(26)

Since the input voltage is passed to the system directly, $V_{IN\_MAX} = V_{SYS\_MAX}$, and both charge mode and boost mode have the same system current ripple.

For $I_{CC\_MAX} = 2A$, $V_{TC} = 3V$, $V_{IN\_MAX} = 6V$, the maximum ripple current is 1.25A. Select the system capacitors based on the ripple-current temperature rise not exceeding 10°C. For best results, use ceramic capacitors with X7R dielectrics with low ESR and small temperature coefficients. For most applications, use three $22\mu F$ capacitors.

**Selecting the Battery Capacitor (C_BATT)**

$C_{BATT}$ is in parallel with the battery to absorb the high-frequency switching ripple current.

1. **Selecting a Battery Cap in Charge Mode**

$C_{BATT}$ is the output capacitor of the buck converter. The output voltage ripple can be calculated with Equation (27):

$$\Delta V_{BATT} = \frac{\Delta V_{BATT}}{V_{BATT}} = \frac{1 - V_{BATT} / V_{SYS}}{8 \times C_{BATT} \times f_s \times L^{2}}$$  

(27)
2. **Selecting a Battery Cap in Boost Mode**

$C_{BATT}$ is the input capacitor of the boost converter. The input voltage ripple is the same as the output voltage ripple from Equation (27).

Both charge mode and boost mode have the same battery voltage ripple. $C_{BATT}$ can be calculated with Equation (28):

$$C_{BATT} = \frac{1 - V_{TC}/V_{SYS_{MAX}}}{8 \times \Delta r_{BATT_{MAX}} \times f_{SW}^2 \times L} \quad (28)$$

To guarantee a ±0.5% BATT voltage accuracy, the maximum BATT voltage ripple must not exceed 0.5% (e.g.: 0.2%). The worst-case scenario occurs at the minimum battery voltage of the CC charge with the maximum input voltage.

For $V_{SYS_{MAX}} = 6V$, $V_{CC_{MIN}} = V_{TC} = 3V$, $L = 2.2\mu H$, $f_{SW} = 600kHz$, $\Delta r_{BATT_{MAX}} = 0.2\%$, and $C_{BATT}$ is 39$\mu F$.

Two 22$\mu F$ ceramic capacitors with X7R dielectrics capacitor in parallel are sufficient.

**PCB Layout Guidelines**

Efficient PCB layout is critical for specified noise, efficiency, and stability requirements. For best results, refer to Figure 15 and follow the guidelines below.

1. Route the power stage adjacent to its ground.
2. Minimize the high-side switching node (SW, inductor) trace lengths in the high-current paths.
3. Keep the switching node short and away from all small control signals, especially the feedback network.
4. Place the input capacitor as close to VIN and PGND as possible.
5. Place the local power input capacitors connected from SYS to PGND as close to the IC as possible.
6. Place the output inductor close to the IC.
7. Connect the output capacitor between the inductor and PGND of the IC.
8. Connect the power pads for IN, SYS, SW, BATT, and PGND to as many coppers planes on the board as possible for high-current applications. This improves thermal performance because the board conducts heat away from the IC.
9. Connect a ground plane to the PCB directly to the return of all components through vias (e.g.: two vias per capacitor for power-stage capacitors, one via per capacitor for small-signal components).
10. Use a star ground design approach to keep circuit block currents isolated (power-signal/control-signal). This reduces noise coupling and ground-bounce issues. A single ground plane for this design gives good results.
11. Place ISET, OLIM, and ILIM resistors very close to their respective IC pins.
Design Example

Table 3 is a design example following the application guidelines for the specifications below.

| $V_{IN}$ | 5V/500mA for USB  
| 5V/3A for adapter  
| Charge | 3.7V / 2.5A  
| Discharge | 4.78V / 2.1A  
| $f_{SW}$ | 600kHz 

Figure 16 shows the detailed application schematic. The typical performance characteristics section shows the typical performance and circuit waveforms. For more possible applications of this device, please refer to the related evaluation board datasheet.
TYPICAL APPLICATION CIRCUIT

Figure 16: Typical Application Circuit of MP2637A with USB Connectors
PACKAGE INFORMATION

QFN-24 (4mmx4mm)

NOTE:

1) ALL DIMENSIONS ARE IN MILLIMETERS.
2) EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
3) LEAD COPLANARITY SHALL BE 0.10 MILLIMETERS MAX.
4) JEDEC REFERENCE IS MO-220.
5) DRAWING IS NOT TO SCALE.

RECOMMENDED LAND PATTERN